



LM733/LM733C Differential Amplifier

General Description

The LM733/LM733C is a two-stage, differential input, differential output, wide-band video amplifier. The use of internal series-shunt feedback gives wide bandwidth with low phase distortion and high gain stability. Emitter-follower outputs provide a high current drive, low impedance capability. Its 120 MHz bandwidth and selectable gains of 10, 100, 400 without need for frequency compensation, make it a very useful circuit for memory element drivers, pulse amplifiers, and wide band linear gain stages.

The LM733 is specified for operation over the -55°C to $+125^{\circ}\text{C}$ military temperature range. The LM733C is specified for operation over the 0°C to $+70^{\circ}\text{C}$ temperature range.

Features

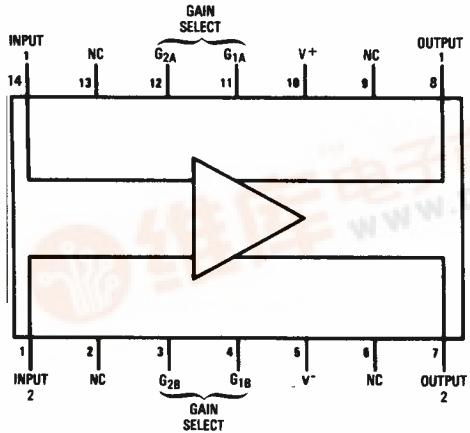
- 120 MHz bandwidth
- 250 k Ω input resistance
- Selectable gains of 10, 100, 400
- No frequency compensation
- High common mode rejection ratio at high frequencies

Applications

- Magnetic tape systems
- Disk file memories
- Thin and thick film memories
- Woven and plated wire memories
- Wide band video amplifiers

Connection Diagrams

Dual-In-Line Package

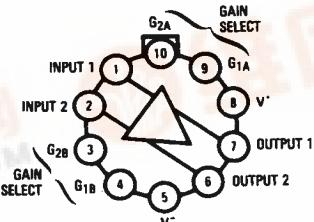


Top View

Order Number LM733CN
See NS Package Number N14A

TL/H/7866-1

Metal Can Package



TL/H/7866-2

Note: Pin 5 connected to case.

Top View

Order Number LM733H or LM733CH
See NS Package Number H10D

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Differential Input Voltage	$\pm 5V$	Power Dissipation (Note 1)	500 mW
Common Mode Input Voltage	$\pm 6V$	Junction Temperature	+150°C
V _{CC}	$\pm 8V$	Storage Temperature Range	-65°C to +150°C
Output Current	10 mA	Operating Temperature Range	-55°C to +125°C
		LM733	0°C to +70°C
		LM733C	260°C

Electrical Characteristics ($T_A = 25^\circ C$, unless otherwise specified, see test circuits, $V_S = \pm 6.0V$)

Characteristics	Test Circuit	Test Conditions	LM733			LM733C			Units
			Min	Typ	Max	Min	Typ	Max	
Differential Voltage Gain Gain 1 (Note 2) Gain 2 (Note 3) Gain 3 (Note 4)	1	$R_L = 2\text{ k}\Omega$ $V_{OUT} = 3\text{ Vp-p}$	300	400	500	250	400	600	
			90	100	110	80	100	120	
			9.0	10	11	8.0	10	12	
Bandwidth Gain 1 Gain 2 Gain 3	2	$V_{OUT} = 1\text{ Vp-p}$		40			40		MHz
				90			90		
				120			120		
Rise Time Gain 1 Gain 2 Gain 3	2	$V_{OUT} = 1\text{ Vp-p}$		10.5			10.5		ns
				4.5	10		4.5	12	
				2.5			2.5		
Propagation Delay Gain 1 Gain 2 Gain 3	2	$V_{OUT} = 1\text{ Vp-p}$		7.5			7.5		ns
				6.0	10		6.0	10	
				3.6			3.6		
Input Resistance Gain 1 Gain 2 Gain 3			20	4.0		10	4.0		kΩ
				30			30		
				250			250		
Input Capacitance		Gain 2		2.0			2.0		pF
Input Offset Current				0.4	3.0		0.4	5.0	μA
Input Bias Current				9.0	20		9.0	30	μA
Input Noise Voltage		BW = 1 kHz to 10 MHz		12			12		μVrms
Input Voltage Range	1		±1.0			±1.0			V
Common Mode Rejection Ratio Gain 2 Gain 2	1	$V_{CM} = \pm 1V f \leq 100\text{ kHz}$ $V_{CM} = \pm 1V f = 5\text{ MHz}$	60	86		60	86		dB
				60			60		
Supply Voltage Rejection Ratio Gain 2	1	$\Delta V_S = \pm 0.5V$	50	70		50	70		dB
Output Offset Voltage Gain 1 Gain 2 and 3	1	$R_L = \infty$		0.6	1.5		0.6	1.5	V
				0.35	1.0		0.35	1.5	
Output Common Mode Voltage	1	$R_L = \infty$	2.4	2.9	3.4	2.4	2.9	3.4	V
Output Voltage Swing	1	$R_L = 2k$	3.0	4.0		3.0	4.0		
Output Sink Current			2.5	3.6		2.5	3.6		mA
Output Resistance				20			20		Ω
Power Supply Current	1	$R_L = \infty$		18	24		18	24	mA

Electrical Characteristics (Continued)

(The following specifications apply for $-55^{\circ}\text{C} < T_A < 125^{\circ}\text{C}$ for the LM733 and $0^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$ for the LM733C, $V_S = \pm 6.0\text{V}$)

Characteristics	Test Circuit	Test Conditions	LM733			LM733C			Units
			Min	Typ	Max	Min	Typ	Max	
Differential Voltage Gain									
Gain 1			200		600	250		600	
Gain 2			80		120	80		120	
Gain 3			8.0		12.0	8.0		12.0	
Input Resistance Gain 2	1	$R_L = 2\text{k}\Omega, V_{\text{OUT}} = 3\text{Vp-p}$		8			8		$\text{k}\Omega$
Input Offset Current						5		6	μA
Input Bias Current						40		40	μA
Input Voltage Range	1			± 1			± 1		V
Common Mode Rejection Ratio									
Gain 2	1	$V_{\text{CM}} = \pm 1\text{V}$, $f \leq 100\text{ kHz}$	50			50			dB
Supply Voltage Rejection Ratio									
Gain 2	1	$\Delta V_S = \pm 0.5\text{V}$	50			50			dB
Output Offset Voltage									
Gain 1	1	$R_L = \infty$				1.5		1.5	V
Gain 2 and 3						1.2		1.5	V
Output Voltage Swing	1	$R_L = 2\text{k}$	2.5			2.8			V_{pp}
Output Sink Current				2.2			2.5		mA
Power Supply Current	1	$R_L = \infty$				27		27	mA

Note 1: The maximum junction temperature of the LM733 is 150°C , while that of the LM733C is 100°C . For operation at elevated temperatures devices in the TO-100 package must be derated based on a thermal resistance of 150°C/W junction to ambient or 45°C/W junction to case. Thermal resistance of the dual-in-line package is 90°C/W .

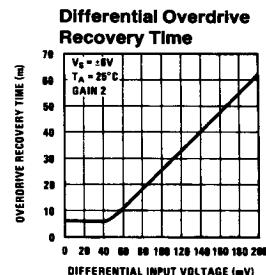
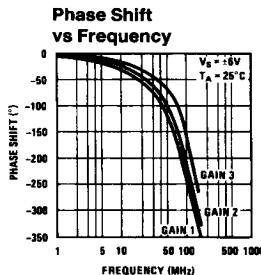
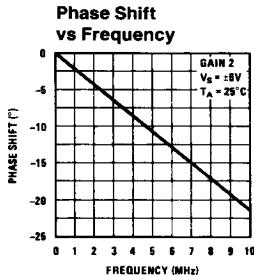
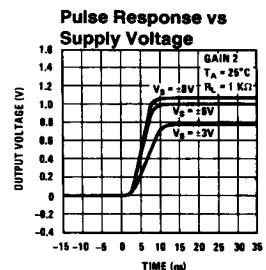
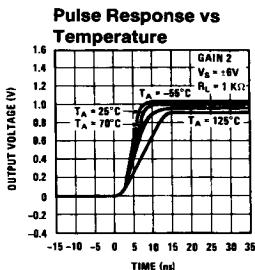
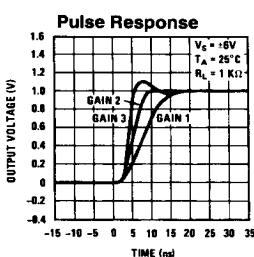
Note 2: Pins G1A and G1B connected together.

Note 3: Pins G2A and G2B connected together.

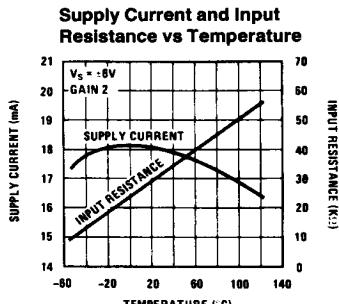
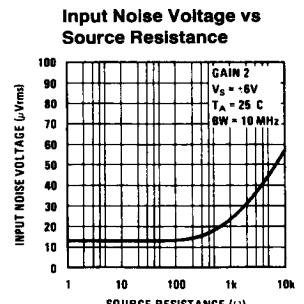
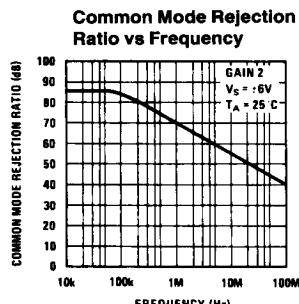
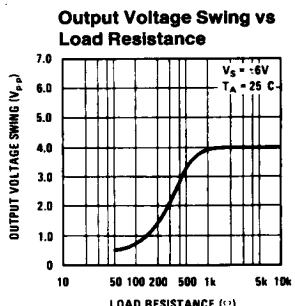
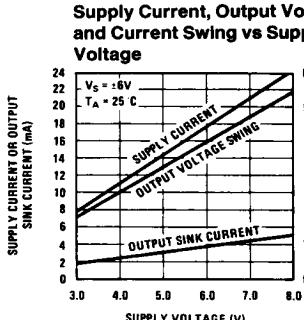
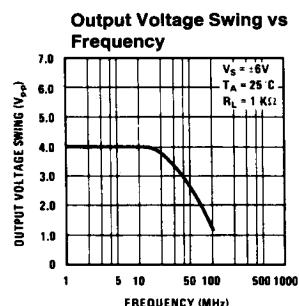
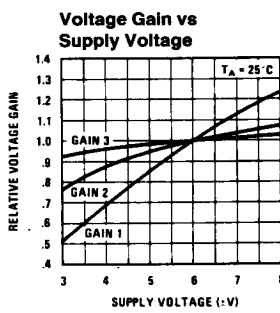
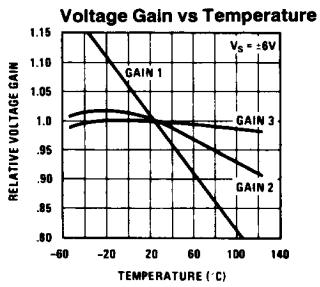
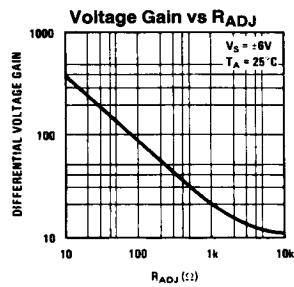
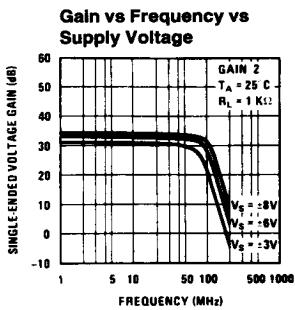
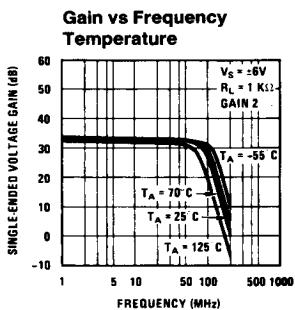
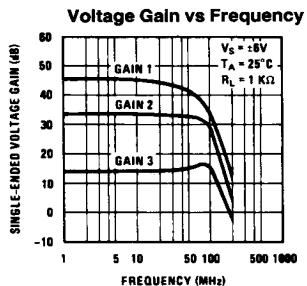
Note 4: Gain select pins open.

Note 5: Refer to RETS733X drawing for specifications of LM733H version.

Typical Performance Characteristics

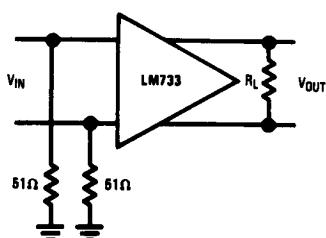


Typical Performance Characteristics (Continued)



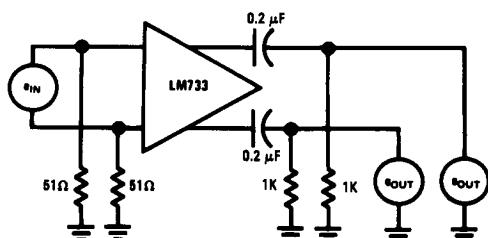
Test Circuits

Test Circuit 1



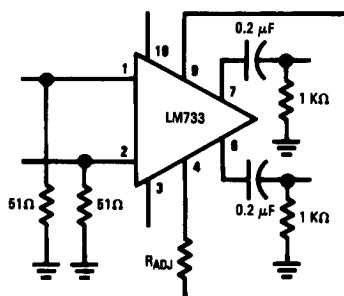
TL/H/7886-3

Test Circuit 2



TL/H/7886-4

Voltage Gain Adjust Circuit

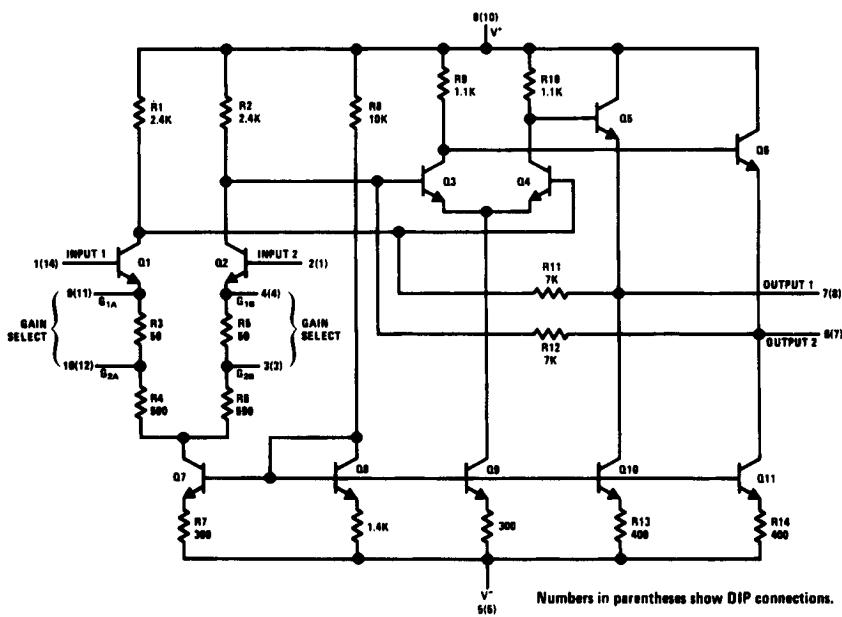


TL/H/7886-5

 $V_S = 8V, T_A = 25^\circ C$

(Pin numbers apply to TO-5 package)

Schematic Diagram



Numbers in parentheses show DIP connections.

TL/H/7886-8